

LM3202

650mA Miniature, Adjustable, Step-Down DC-DC Converter for RF Power Amplifiers

General Description

The LM3202 is a DC-DC converter optimized for powering RF power amplifiers (PAs) from a single Lithium-Ion cell, however they may be used in many other applications. It steps down an input voltage from 2.7V to 5.5V to a variable output voltage from 1.3V to 3.16V. Output voltage is set using a $V_{\rm CON}$ analog input for controlling power levels and efficiency of the RF PA. The LM3202 offers superior performance for mobile phones and similar RF PA applications. Fixed-frequency PWM operation minimizes RF interference. Shutdown function turns the device off and reduces battery consumption to 0.01 μ A (typ.). The LM3202 is available in a 8-pin lead free micro SMD package. A high switching frequency (2 MHz) allows use of tiny surface-mount components. Only three small external surface-mount components, an inductor and two ceramic capacitors are required.

Features

- 2 MHz (typ.) PWM Switching Frequency
- Operates from a single Li-lon cell (2.7V to 5.5V)
- Variable Output Voltage (1.3V to 3.16V)
- Fast Output Voltage Transient (1.3V to 3.16V in 20µs)
- 650mA Maximum load capability
- High Efficiency (96% Typ at 3.6V_{IN}, 3.16V_{OUT} at 400mA) from internal synchronous rectification
- 8-pin micro SMD Package
- Current Overload Protection
- Thermal Overload Protection
- Soft Start function

Applications

- Cellular Phones
- Hand-Held Radios
- RF PC Cards
- Battery Powered RF Devices

Typical Application

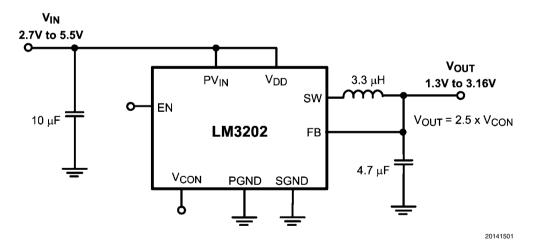
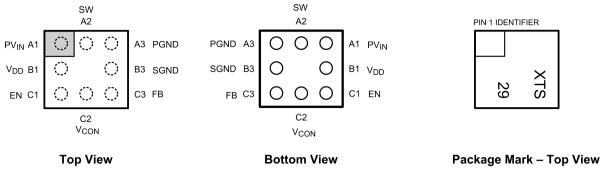


FIGURE 1. LM3202 Typical Application

Connection Diagrams



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8-Bump Thin Micro SMD Package, Large Bump NS Package Number TLA08HPA

Order Information

Order Number	Package Marking (Note)	Supplied As
LM3202TL	XTS/29	250 units, Tape-and-Reel
LM3202TLX	XTS/29	3000 units, Tape-and-Reel

Note: The actual physical placement of the package marking will vary from part to part. The package marking "X" designates the date code. "T" is a NSC internal code for die traceability. "S" designates the device type as switcher device. Both will vary considerably. "29" identifies the device (part number, option, etc.).

Pin Descriptions

Pin #	Name	Description
A1	PV_{IN}	Power Supply Voltage Input to the internal PFET switch.
B1	V_{DD}	Analog Supply Input.
C1	EN	Enable Input. Set this digital input high for normal operation. For shutdown, set low.
C2	V _{CON}	Voltage Control Analog input. V _{CON} controls V _{OUT} in PWM mode.
C3	FB	Feedback Analog Input. Connect to the output at the output filter capacitor.
В3	SGND	Analog and Control Ground
A3	PGND	Power Ground
A2	SW	Switch node connection to the internal PFET switch and NFET synchronous rectifier.
		Connect to an inductor with a saturation current rating that exceeds the maximum Switch Peak Current Limit specification of the LM3202.

Absolute Maximum Ratings (Notes 1, 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Continuous Power Dissipation

(Note 3) Internally Limited Junction Temperature (T_{J-MAX}) +150°C

Storage Temperature Range -65°C to +150°C

Maximum Lead Temperature (Soldering, 10 sec) ESD Rating (Notes 4, 13)

Human Body Model:

Machine Model:

+260°C 2 kV 200V

Operating Ratings (Notes 1, 2)

Input Voltage Range 2.7V to 5.5V

Recommended Load Current 0mA to 650mA

Junction Temperature (T_J) Range -30°C to +125°C

Ambient Temperature (T_A) Range -30°C to +85°C

Thermal Properties

Junction-to-Ambient Thermal 100°C/W

Resistance (θ_{JA}), TLA08 Package

(Note 6)

Electrical Characteristics (Notes 2, 7, 8) Limits in standard typeface are for $T_A = T_J = 25^{\circ}C$. Limits in **boldface** type apply over the full operating ambient temperature range ($-30^{\circ}C \le T_A = T_J \le +85^{\circ}C$). Unless otherwise noted, all specifications apply to LM3202 with: $PV_{IN} = V_{DD} = EN = 3.6V$.

Symbol	Parameter	Conditions	Min	Тур	Max	Units
/ _{FB, MIN}	Feedback Voltage at minimum setting	V _{CON} = 0.4V(Note 8)	1.21	1.30	1.39	V
/ _{FB}	Feedback Voltage	V _{CON} = 1.1V(Note 8)	2.693	2.75	2.835	V
/ _{FB, MAX}	Feedback Voltage at maximum setting	V _{CON} = 1.4V(Note 8)	3.03	3.17	3.29	V
SHDN	Shutdown supply current	$EN = SW = V_{CON} = 0V,$ (Note 9)		0.01	2	μΑ
Q	DC bias current into V _{DD}	V _{CON} = 1V, FB = 0V, No Switching (Note 10)		1	1.4	mA
R _{DSON(P)}	Pin-pin resistance for PFET	I _{SW} = 200mA		140	200 230	mΩ
R _{DSON(N)}	Pin-pin resistance for NFET	I _{SW} = -200mA		300	415 485	mΩ
LIM,PFET	Switch peak current limit	(Note 11)	935	1100	1200	mA
osc	Internal oscillator frequency		1.7	2	2.3	MHz
/ _{IH,EN}	Logic high input threshold		1.2			V
/ _{IL,EN}	Logic low input threshold				0.5	V
PIN,ENABLE	Pin pull down current			5	10	μA
V _{CON,MIN}	V _{CON} Threshold Commanding V _{FB,MIN}	V _{CON} swept down(Note 8)	0.484	0.52	0.556	V
V _{CON,MAX}	V _{CON} Threshold Commanding V _{FB,MAX}	V _{CON} swept up(Note 8)	1.208	1.27	1.312	V
Z _{CON}	V _{CON} input resistance		100			kΩ
Gain	V _{CON} to V _{OUT} Gain	0.556V ≤ V _{CON} ≤ 1.208V		2.5		V/V

System Characteristics The following spec table entries are guaranteed by design providing the component values in the typical application circuit are used. **These parameters are not guaranteed by production testing.** Min and Max limits apply over the full operating ambient temperature range (-30° C \leq T_A \leq 85°C) and over the V_{IN} range = 2.7V to 5.5V unless otherwise specified, Typical values are at T_A = 25°C, PV_{IN} = V_{DD} = EN = 3.6V unless otherwise specified, L = 3.3μH, DCR of L \leq 100mΩ, C_{IN} = 10μF, 0603, 6.3V (4.7μFII4.7μF, 0603, 6.3V can also be used), C_{OUT} = 4.7μF, 0603, 6.3V

Symbol	Parameter	Conditions	Min	Тур	Max	Units
T _{RESPONSE}	Time for V _{OUT} to rise from 1.3V to 3.16V	V_{IN} = 4.2V, C_{OUT} = 4.7 μ F, L = 3.3 μ H, R_{LOAD} = 5 Ω		20	30	
	Time for V _{OUT} to fall from 3.16V to 1.3V	V_{IN} = 4.2V, C_{OUT} = 4.7 μ F, L = 3.3 μ H, R_{LOAD} = 10 Ω		20	30	μs
C _{CON}	V _{CON} input capacitance	V _{CON} = 1V, Test frequency = 100 kHz			20	pF
Linearity	Linearity in control range 0.556V to 1.208V	V _{IN} = 3.6V Monotonic in nature	-3		+3	%
I _{CON}	Control pin input current		-10		10	μA
T _{_ON}	Turn on time (time for output to reach 3.16V from Enable low to high transition)	EN = Low to High, $V_{IN} = 4.2V$, $V_{O} = 3.16V$, $C_{OUT} = 4.7\mu\text{F}$, $I_{OUT} \le 1\text{mA}$		210	750	μs
η	Efficiency	$V_{IN} = 3.6V, V_{OUT} = 1.3V, I_{OUT} = 90mA$		87		%
	$(L = 3.3\mu H, DCR ≤ 100mΩ)$	V _{IN} = 3.6V, V _{OUT} = 3.16V, I _{OUT} = 400mA		96		%
V _{OUT} _ripple	Ripple voltage, PWM mode	$V_{IN} = 3V$ to 4.5V, $V_{OUT} = 1.3V$, $I_{OUT} = 10$ mA to 400mA (Note 12)		10		mVp-p
Line_tr	Line transient response	V_{IN} = 600mV perturbance, over Vin range 3V to 5.5V T_{RISE} = T_{FALL} = 10 μ s, V_{OUT} = 1.3V, I_{OUT} = 100mA		50		mVpk
Load_tr	Load transient response	V_{IN} = 3.1/3.6/4.5V, V_{OUT} = 1.3V, transients up to 100mA, T_{RISE} = T_{FALL} = 10 μ s		50		mVpk
PSRR	$V_{IN} = 3.6V, V_{OUT} = 1.3V,$ $I_{OUT} = 100mA$	sine wave perturbation frequency = 10kHz, amplitude = 100mVp-p		40		dB

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the component may occur. Operating Ratings are conditions under which operation of the device is guaranteed. Operating Ratings do not imply guaranteed performance limits. For guaranteed performance limits and associated test conditions, see the Electrical Characteristics tables.

Note 2: All voltages are with respect to the potential at the GND pins. The LM3202 is designed for mobile phone applications where turn-on after power-up is controlled by the system controller and where requirements for a small package size overrule increased die size for internal Under Voltage Lock-Out (UVLO) circuitry. Thus, it should be kept in shutdown by holding the EN pin low until the input voltage exceeds 2.7V.

Note 3: Internal thermal shutdown circuitry protects the device from permanent damage. Thermal shutdown engages at T_J = 150°C (typ.) and disengages at T_J = 130°C (typ.).

Note 4: The Human body model is a 100pF capacitor discharged through a 1.5kΩ resistor into each pin. (MIL-STD-883 3015.7) The machine model is a 200pF capacitor discharged directly into each pin.

Note 5: In applications where high power dissipation and/or poor package thermal resistance is present, the maximum ambient temperature may have to be derated. Maximum ambient temperature $(T_{J-MAX-OP} = 125^{\circ}C)$, the maximum power dissipation of the device in the application (P_{D-MAX}) , and the junction-to ambient thermal resistance of the part/package in the application (θ_{JA}) , as given by the following equation: $T_{A-MAX} = T_{J-MAX-OP} - (\theta_{JA} \times P_{D-MAX})$.

Note 6: Junction-to-ambient thermal resistance (θ_{JA}) is taken from thermal measurements, performed under the conditions and guidelines set forth in the JEDEC standard JESD51-7. A 4 layer, 4" x 4", 2/1/1/2 oz. Cu board as per JEDEC standards is used for the measurements.

Note 7: Min and Max limits are guaranteed by design, test, or statistical analysis. Typical numbers are not guaranteed, but do represent the most likely norm. Due to the pulsed nature of the testing $T_A = T_J$ for the electrical characteristics table.

Note 8: The parameters in the electrical characteristics table are tested under open loop conditions at $PV_{IN} = V_{DD} = 3.6V$. For performance over the input voltage range and closed loop results refer to the datasheet curves.

Note 9: Shutdown current includes leakage current of PFET.

Note 10: I_O specified here is when the part is operating at 100% duty cycle.

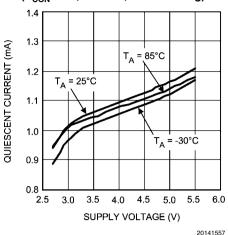
Note 11: Current limit is built-in, fixed, and not adjustable. Refer to datasheet curves for closed loop data and its variation with regards to supply voltage and temperature. Electrical Characteristic table reflects open loop data (FB = 0V and current drawn from SW pin ramped up until cycle by cycle limit is activated). Closed loop current limit is the peak inductor current measured in the application circuit by increasing output current until output voltage drops by 10%.

Note 12: Ripple voltage should measured at C_{OUT} electrode on good layout PC board and under condition using suggested inductors and capacitors.

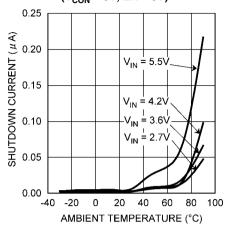
Note 13: National Semiconductor recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper ESD handling techniques can result in damage.

Typical Performance Characteristics (Circuit in *Figure 3*, $PV_{IN} = V_{DD} = EN = 3.6V$, L = 3.3uH, DCR of $L \le 100m\Omega$, $C_{IN} = 10uF$, 0603, 6.3V (4.7uFII4.7uF, 0603, 6.3V can be used), $C_{OUT} = 4.7uF$, 0603, 6.3V unless otherwise noted)

Quiescent Current vs Supply Voltage (V_{CON} = 2V, FB = 0V, No Switching)

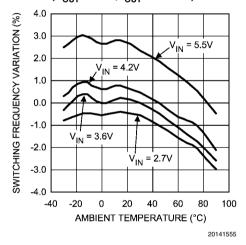


Shutdown Current vs Temperature $(V_{CON} = 0V, EN = 0V)$

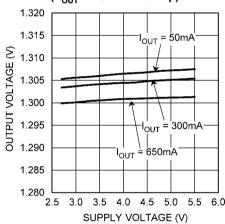


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Switching Frequency Variation vs Temperature ($V_{OUT} = 1.3V$, $I_{OUT} = 200mA$)

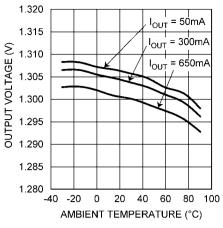


Output Voltage vs Supply Voltage (V_{OUT} = 1.3V: low clamp)



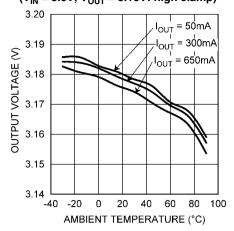
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Output Voltage vs Temperature $(V_{IN} = 3.6V, V_{OUT} = 1.3V: low clamp)$



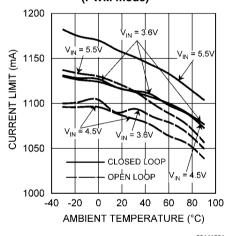
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Output Voltage vs Temperature $(V_{IN} = 3.6V, V_{OUT} = 3.16V: high clamp)$

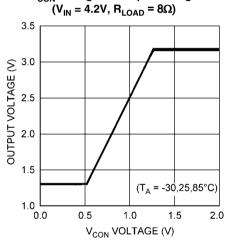


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Open/Closed Loop Current Limit vs Temperature (PWM mode)

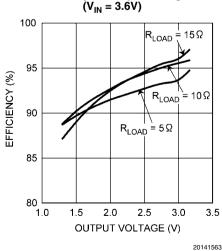


V_{CON} Voltage vs Output Voltage

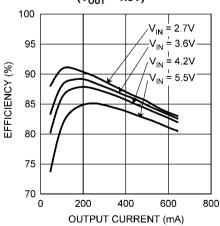


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Efficiency vs Output Voltage (V_{IN} = 3.6V)

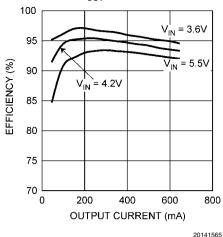


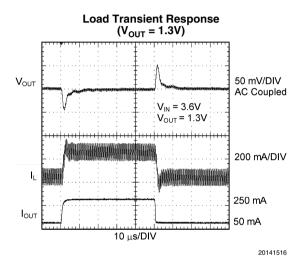
Efficiency vs Output Current (V_{OUT} = 1.3V)

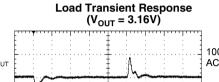


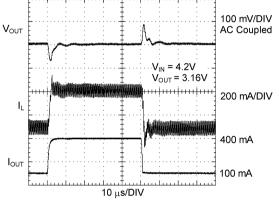
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Efficiency vs Output Current (V_{OUT} = 3.16V)

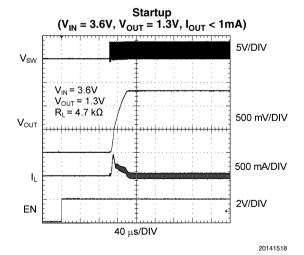


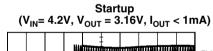


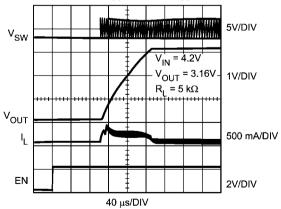




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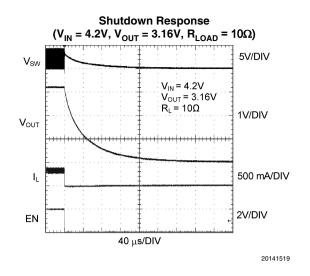


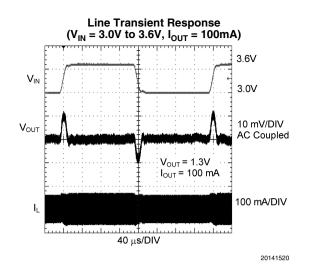




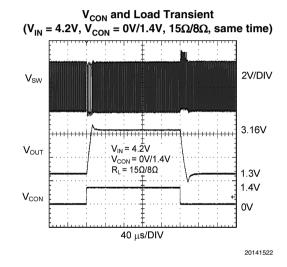
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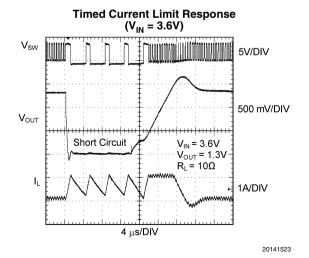
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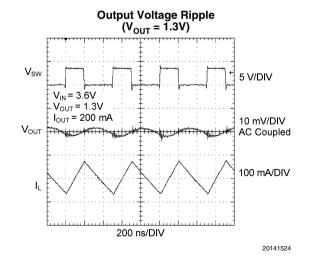


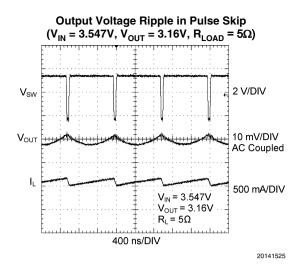


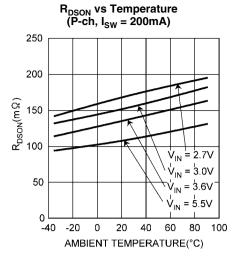
 $V_{CON} \text{ Voltage Response} \\ (V_{IN} = 4.2V, V_{CON} = 0V/1.4V, R_{LOAD} = 10\Omega) \\ V_{SW} \\ V_{OUT} \\ V_{CON} = 4.2V \\ V_{CON} = 0V/1.4V \\ R_L = 10\Omega \\ 1.3V \\ 1.4V \\ 0V \\ 20141521$



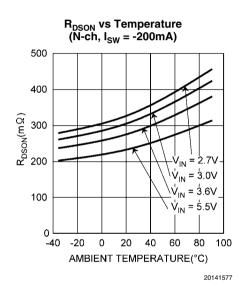


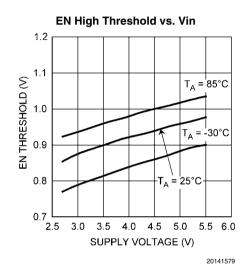


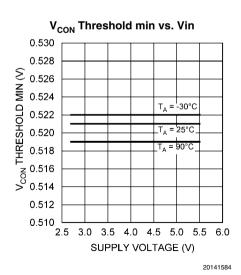


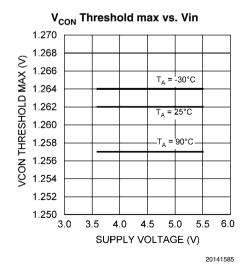


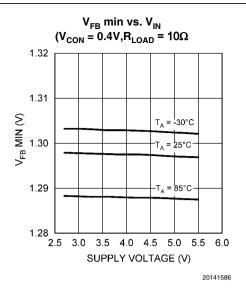
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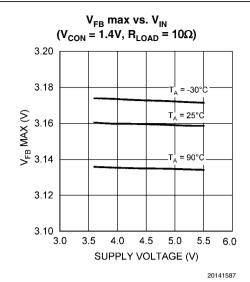












Block Diagram

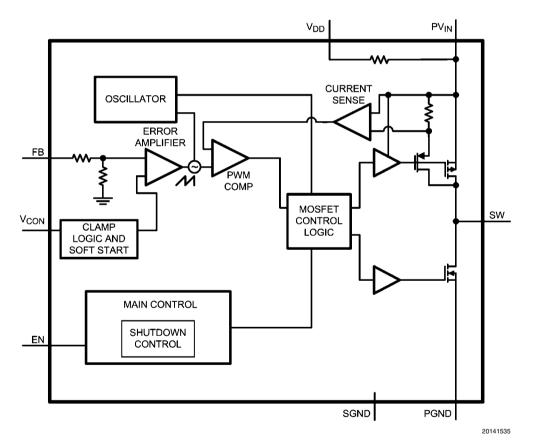


FIGURE 2. Functional Block Diagram

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Operation Description

The LM3202 is a simple, step-down DC-DC converter optimized for powering RF power amplifiers (PAs) in mobile phones, portable communicators, and similar battery powered RF devices. It is designed to allow the RF PA to operate at maximum efficiency over a wide range of power levels from a single Li-Ion battery cell. It is based on a current-mode buck architecture, with synchronous rectification for high efficiency.

It is designed for a maximum load capability of 650mA in PWM mode.

Maximum load range may vary from this depending on input voltage, output voltage and the inductor chosen.

Efficiency is typically around 96% for a 400mA load with 3.16V output, 3.6V input. The output voltage is dynamically programmable from 1.3V (typ) to 3.16V (typ) by adjusting the voltage on the control pin without the need for external feedback resistors. This ensures longer battery life by being able

to change the PA supply voltage dynamically depending on its transmitting power.

Additional features include current overload protection, thermal overload shutdown and soft start.

The LM3202 is constructed using a chip-scale 8-pin micro SMD package. This package offers the smallest possible size, for space-critical applications such as cell phones, where board area is an important design consideration. Use of a high switching frequency (2MHz) reduces the size of external components. As shown in *Figure 1*, only three external power components are required for implementation. Use of a

micro SMD package requires special design considerations for implementation. (See Micro SMD Package Assembly and use in the Applications Information section.) Its fine bump-pitch requires careful board design and precision assembly equipment. Use of this package is best suited for opaque-case applications, where its edges are not subject to high-intensity ambient red or infrared light. Also, the system controller should set EN low during power-up and other low supply voltage conditions. (See Shutdown Mode in the Device Information section.)

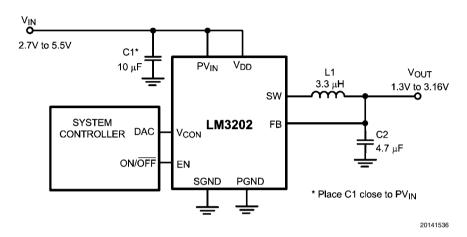


FIGURE 3. Typical Operating System Circuit

Circuit Operation

Referring to Figure 1 and Figure 2, the LM3202 operates as follows. During the first part of each switching cycle, the control block in the LM3202 turns on the internal PFET (Pchannel MOSFET) switch. This allows current to flow from the input through the inductor to the output filter capacitor and load. The inductor limits the current to a ramp with a slope of around (V_{IN} - V_{OUT}) / L, by storing energy in a magnetic field. During the second part of each cycle, the controller turns the PFET switch off, blocking current flow from the input, and then turns the NFET (N-channel MOSFET) synchronous rectifier on. In response, the inductor's magnetic field collapses, generating a voltage that forces current from ground through the synchronous rectifier to the output filter capacitor and load. As the stored energy is transferred back into the circuit and depleted, the inductor current ramps down with a slope around V_{OUT} / L. The output filter capacitor stores charge when the inductor current is high, and releases it when low, smoothing the voltage across the load.

The output voltage is regulated by modulating the PFET switch on time to control the average current sent to the load. The effect is identical to sending a duty-cycle modulated rectangular wave formed by the switch and synchronous rectifier at SW to a low-pass filter formed by the inductor and output filter capacitor. The output voltage is equal to the average voltage at the SW pin.

While in operation, the output voltage is regulated by switching at a constant frequency and then modulating the energy per cycle to control power to the load. Energy per cycle is set by modulating the PFET switch on-time pulse width to control the peak inductor current. This is done by comparing the signal from the current-sense amplifier with a slope compensated error signal from the voltage-feedback error amplifier. At

the beginning of each cycle, the clock turns on the PFET switch, causing the inductor current to ramp up. When the current sense signal ramps past the error amplifier signal, the PWM comparator turns off the PFET switch and turns on the NFET synchronous rectifier, ending the first part of the cycle. If an increase in load pulls the output down, the error amplifier output increases, which allows the inductor current to ramp higher before the comparator turns off the PFET. This increases the average current sent to the output and adjusts for the increase in the load.

Before appearing at the PWM comparator, a slope compensation ramp from the oscillator is subtracted from the error signal for stability of the current feedback loop. The minimum on time of PFET in PWM mode is 50ns (typ.)

Shutdown Mode

Setting the EN digital pin low (<0.5V) places the LM3202 in a 0.01 μ A (typ.) Shutdown mode. During shutdown, the PFET switch, NFET synchronous rectifier, reference voltage source, control and bias circuitry of the LM3202 are turned off. Setting EN high (>1.2V) enables normal operation.

EN should be set low to turn off the LM3202 during power-up and under voltage conditions when the power supply is less than the 2.7V minimum operating voltage. The LM3202 is designed for compact portable applications, such as mobile phones. In such applications, the system controller determines power supply sequencing and requirements for small package size outweigh the additional size required for inclusion of UVLO (Under Voltage Lock-Out) circuitry.

Internal Synchronous Rectification

The LM3202 uses an internal NFET as a synchronous rectifier to reduce rectifier forward voltage drop and associated power

loss. Synchronous rectification provides a significant improvement in efficiency whenever the output voltage is relatively low compared to the voltage drop across and ordinary rectifier diode.

The internal NFET synchronous rectifier is turned on during the inductor current down slope in the second part of each cycle. The synchronous rectifier is turned off prior to the next cycle. The NFET is designed to conduct through its intrinsic body diode during transient intervals before it turns on, eliminating the need for an external diode.

Current Limiting

A current limit feature allows the LM3202 to protect itself and external components during overload conditions. In PWM mode, an 1200mA (max.) cycle-by-cycle current limit is normally used. If an excessive load pulls the output voltage down to approximately 0.375V, then the device switches to a timed current limit mode. In timed current limit mode the internal PFET switch is turned off after the current comparator trips and the beginning of the next cycle is inhibited for 3.5us to force the instantaneous inductor current to ramp down to a safe value. The synchronous rectifier is off in timed current limit mode. Timed current limit prevents the loss of current control seen in some products when the output voltage is pulled low in serious overload conditions.

Dynamically Adjustable Output Voltage

The LM3202 features dynamically adjustable output voltage to eliminate the need for external feedback resistors. The output can be set from $V_{FB,MIN}$ to $V_{FB,MAX}$ by changing the voltage on the analog V_{CON} pin. This feature is useful in PA applications where peak power is needed only when the handset is far away from the base station or when data is being transmitted. In other instances the transmitting power can be reduced. Hence the supply voltage to the PA can be reduced, promoting longer battery life. See Setting the Output Voltage in the Application Information section for further details.

Thermal Overload Protection

The LM3202 has a thermal overload protection function that operates to protect itself from short-term misuse and overload conditions. When the junction temperature exceeds around 150°C, the device inhibits operation. Both the PFET and the NFET are turned off in PWM mode. When the temperature drops below 125°C, normal operation resumes. Prolonged operation in thermal overload conditions may damage the device and is considered bad practice.

Application Information

SETTING THE OUTPUT VOLTAGE

The LM3202 features a pin-controlled variable output voltage to eliminate the need for external feedback resistors. It can be programmed for an output voltage from 1.3V (typ) to 3.16V (typ) by setting the voltage on the $V_{\rm CON}$ pin, as in *Table 1*.

TABLE 1. Output Voltage Selection

$V_{CON}(V)$	V _{OUT} (V)
V _{CON} ≤ 0.484	$V_{FB,MIN}$
0.556 < V _{CON} <1.208	$V_{OUT} = 2.5 \times V_{CON}$
V _{CON} ≥ 1.312	$V_{FB,MAX}$

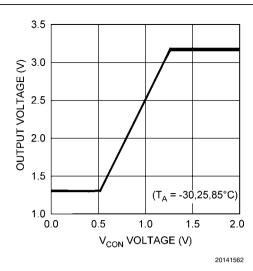


FIGURE 4. V_{CON} Voltage vs Output Voltage

Refer to Figure 4 for the relation between V_{OUT} and V_{CON} . When the control pin voltage is between 0.556V and 1.208V, the output voltage will vary in a monotonic fashion with respect to the voltage on the control pin as per the above *Table 1* equation.

Internally the control pin is clamped before it is fed to the error amplifier inputs. If voltage on the control pin is less than 0.484V, the output voltage is regulated at $V_{\rm FB,MIN}$ and if the voltage is greater than 1.312V, the output is regulated at $V_{\rm FB,MAX}$.

INDUCTOR SELECTION

A 3.3µH inductor with saturation current rating over 1200mA and low inductance drop at the full DC bias condition is recommended for almost all applications. The inductor's DC resistance should be less than 0.2Ω for good efficiency. For low dropout voltage, lower DCR inductors are advantageous. The lower limit of acceptable inductance is 2.3µH at 1200mA over the operating temperature range. Full attention should be paid to this limit, because some small inductors show large inductance drops at high DC bias. These can not be used with the LM3202. Taiyo-Yuden NR3015T3R3M is an example of an inductor with the lowest acceptable limit (as of Nov./05). $Table\ 2$ suggests some inductors and suppliers.

TABLE 2. Suggested inductors and their suppliers

Model	Size (WxLxH) [mm]	Vendor
NR3015T3R3M	3.0 x 3.0 x 1.5	Taiyo-
		Yuden
DO3314-332MXC	3.3 x 3.3 x 1.4	Coilcraft

If a smaller inductance inductor is used in the application, the LM3202 may become unstable during line and load transients and $V_{\rm CON}$ transient response times may get affected.

For low-cost applications, an unshielded bobbin inductor is suggested. For noise-critical applications, a toroidal or shield-ed-bobbin inductor should be used. A good practice is to lay out the board with footprints accommodating both types for design flexibility. This allows substitution of a low-noise toroidal inductor, in the event that noise from low-cost bobbin models is unacceptable. Saturation occurs when the magnetic flux density from current through the windings of the inductor exceeds what the inductor's core material can support with a corresponding magnetic field. This can cause poor

efficiency, regulation errors or stress to a DC-DC converter like the LM3202.

CAPACITOR SELECTION

The LM3202 is designed for use with ceramic capacitors for its input and output filters. Use a 10uF ceramic capacitor for input and a 4.7uF ceramic capacitor for output. They should maintain at least 50% capacitance at DC bias and temperature conditions. Ceramic capacitors types such as X5R, X7R are recommended for both filters. These provide an optimal balance between small size, cost, reliability and performance for cell phones and similar applications. Table 3 lists some suggested part numbers and suppliers. DC bias characteristics of the capacitors must be considered when selecting the voltage rating and case size of the capacitor. A few manufactures can supply 4.7µF capacitors in the 0805 case size which maintain at least 50% of their value, but TDK is currently the only manufacturer which can provide such capacitors in the 0603 case size. As of November, 2005, no manufacture can supply 10µF capacitors in the 0603 case size which maintain 50% of their value. If it is necessary to choose a 0603-size capacitor for V_{IN}, the operation of the LM3202 should be carefully evaluated on the system board. Output capacitors with smaller case sizes mitigate piezo electric vibrations when the output voltage is stepped up and down at fast rates. However, they have a larger percentage drop in value with dc bias. Use of multiple 2.2µF or 1µF capacitors in parallel may also be considered.

TABLE 3. Suggested capacitors and their suppliers

Model	Vendor
0805ZD475KA 4.7μF, 10V	AVX
C1608X5R0J475M, 4.7µF, 6.3V	TDK
C2012X5R0J106M,10µF, 6.3V	TDK

The input filter capacitor supplies AC current drawn by the PFET switch of the LM3202 in the first part of each cycle and reduces the voltage ripple imposed on the input power source. The output filter capacitor absorbs the AC inductor current, helps maintain a steady output voltage during transient load changes and reduces output voltage ripple. These capacitors must be selected with sufficient capacitance and sufficiently low ESR (Equivalent Series Resistance) to perform these functions. The ESR of the filter capacitors is generally a major factor in voltage ripple.

EN PIN CONTROL

Drive the EN pin using the system controller to turn the LM3202 ON and OFF. Use a comparator, Schmidt trigger or logic gate to drive the EN pin. Set EN high (>1.2V) for normal operation and low (<0.5V) for a 0.01µA (typ.) shutdown mode. Set EN low to turn off the LM3202 during power-up and under voltage conditions when the power supply is less than the 2.7V minimum operating voltage. The part is out of regulation when the input voltage is less than 2.7V. The LM3202 is designed for mobile phones where the system controller controls operation mode for maximizing battery life and requirements for small package size outweigh the additional size required for inclusion of UVLO (Under Voltage Lock-Out) circuitry.

Micro SMD PACKAGE ASSEMBLY AND USE

Use of the Micro SMD package requires specialized board layout, precision mounting and careful re-flow techniques, as detailed in National Semiconductor Application Note 1112. Refer to the section *Surface Mount Technology (SMD) As*-

sembly Considerations. For best results in assembly, alignment ordinals on the PC board should be used to facilitate placement of the device. The pad style used with Micro SMD package must be the NSMD (non-solder mask defined) type. This means that the solder-mask opening is larger than the pad size. This prevents a lip that otherwise forms if the solder-mask and pad overlap, from holding the device off the surface of the board and interfering with mounting. See Application Note 1112 for specific instructions how to do this.

The 8-Bump package used for LM3202 has 300micron solder balls and requires 10.82mil pads for mounting on the circuit board. The trace to each pad should enter the pad with a 90° entry angle to prevent debris from being caught in deep corners. Initially, the trace to each pad should be 7mil wide, for a section approximately 7mil long , as a thermal relief. Then each trace should neck up or down to its optimal width. The important criterion is symmetry. This ensures the solder bumps on the LM3202 re-flow evenly and that the device solders level to the board. In particular, special attention must be paid to the pads for bumps A1, A3 and B3. Because PGND and PVIN are typically connected to large copper planes, inadequate thermal relief's can result in late or inadequate reflow of these bumps.

The Micro SMD package is optimized for the smallest possible size in applications with red or infrared opaque cases. Because the Micro SMD package lacks the plastic encapsulation characteristic of larger devices, it is vulnerable to light. Backside metallization and/or epoxy coating, along with frontside shading by the printed circuit board, reduce this sensitivity. However, the package has exposed die edges. In particular, Micro SMD devices are sensitive to light, in the red and infrared range, shining on the package's exposed die edges.

BOARD LAYOUT CONSIDERATIONS

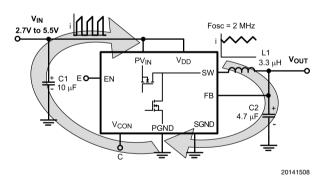
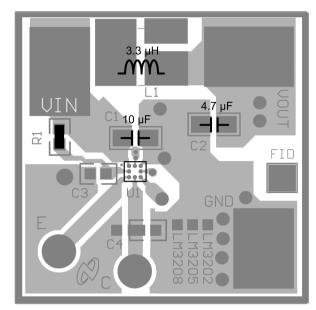


FIGURE 5. Current Loop

The LM3202 converts higher input voltage to lower output voltage with high efficiency. This is achieved with an inductor-based switching topology. During the first half of the switching cycle, the internal PMOS switch turns on, the input voltage is applied to the inductor, and the current flows from P_{VDD} line to the output capacitor (C2) through the inductor. During the second half cycle, the PMOS turns off and the internal NMOS turns on. The inductor current continues to flow via the inductor from the device PGND line to the output capacitor (C2).

Referring to Figure 5, the LM3202 has two major current loops where pulse and ripple current flow. The loop shown in the left hand side is most important, because pulse current shown in Figure 5 flows in this path. The right hand side is next. The current waveform in this path is triangular, as shown in Figure 5. Pulse current has many high-frequency components due

to fast di/dt. Triangular ripple current also has wide high-frequency components. Board layout and circuit pattern design of these two loops are the key factors for reducing noise radiation and stable operation. Other lines, such as from battery to C1(+) and C2(+) to load, are almost DC current, so it is not necessary to take so much care. Only pattern width (current capability) and DCR drop considerations are needed.



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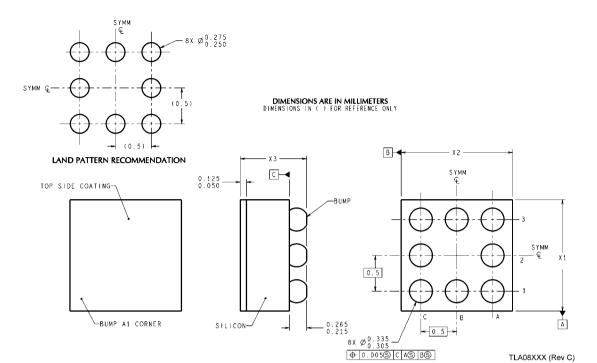
FIGURE 6. Evaluation Board Layout

BOARD LAYOUT FLOW

- Minimize C1, PV_{IN}, and PGND loop. These traces should be as wide and short as possible. This is most important.
- 2. Minimize L1, C2, SW and PGND loop. These traces also should be wide and short. This is the second priority.
- Above layout patterns should be placed on the component side of the PCB to minimize parasitic inductance and resistance due to via-holes. It may be a good idea that the SW to L1 path is routed between C2 (+) and C2(-) land patterns. If vias are used in these large current paths, multiple via-holes should be used if possible.
- Connect C1(-), C2(-) and PGND with wide GND pattern.
 This pattern should be short, so C1(-), C2(-), and PGND should be as close as possible. Then connect to a PCB common GND pattern with as many via-holes as possible.
- SGND should not connect directly to PGND. Connecting these pins under the device should be avoided. (If possible, connect SGND to the common port of C1(-), C2 (-) and PGND.)
- 6. V_{DD} should not be connected directly to PV_{IN} . Connecting these pins under the device should be avoided. It is good idea to connect V_{DD} to the C1(+) to avoid switching noise injection to the V_{DD} line.
- 7. FB line should be protected from noise. It is a good idea to use an inner GND layer (if available) as a shield.

Note: The evaluation board shown in Figure 6 for the LM3202 was designed with these considerations, and it shows good performance. However some aspects have not been optimized because of limitations due to evaluation-specific requirements. The board can be used as a reference, but it is not the best. Please refer questions to a National representative.

Physical Dimensions inches (millimeters) unless otherwise noted



8-Bump Thin Micro SMD, Large Bump
X1 = 1.692mm ± 0.030mm
X2 = 1.844mm ±0.030mm
X3 = 0.600mm ±0.075mm
NS Package Number TLA08HPA

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